

DATA SHEET

74AHC573; 74AHCT573

Octal D-type transparent latch;
3-state

Product specification
File under Integrated Circuits, IC06

1999 Sep 27

Octal D-type transparent latch; 3-state

74AHC573; 74AHCT573

FEATURES

- ESD protection:
HBM EIA/JESD22-A114-A
exceeds 2000 V
MM EIA/JESD22-A115-A
exceeds 200 V
CDM EIA/JESD22-C101
exceeds 1000 V
- Balanced propagation delays
- All inputs have Schmitt-trigger actions
- Common 3-state output enable input
- Functionally identical to the '563' and '373'
- Inputs accept voltages higher than V_{CC}
- For AHC only:
operates with CMOS input levels
- For AHCT only:
operates with TTL input levels
- Specified from
-40 to +85 and +125 °C.

DESCRIPTION

The 74AHC/AHCT573 are high-speed Si-gate CMOS devices and are pin compatible with low power Schottky TTL (LSTTL). They are specified in compliance with JEDEC standard No. 7A.

The 74AHC/AHCT573 are octal D-type transparent latches featuring separate D-type inputs for each latch and 3-state outputs for bus oriented applications. A Latch Enable (LE) input and an Output Enable ($\overline{OE}$) input are common to all latches.

The '573' consists of eight D-type transparent latches with 3-state true outputs. When LE is HIGH, data at the D_n inputs enters the latches. In this condition the latches are transparent, i.e. a latch output will change state each time its corresponding D-input changes.

When LE is LOW the latches store the information that was present at the D-inputs a set-up time preceding the HIGH-to-LOW transition of LE. When $\overline{OE}$ is LOW, the contents of the 8 latches are available at the outputs. When $\overline{OE}$ is HIGH, the outputs go to the high-impedance OFF-state. Operation of the $\overline{OE}$ input does not affect the state of the latches.

The '573' is functionally identical to the '533', '563' and '373', but the '533' and '563' have inverted outputs and the '563' and '373' have a different pin arrangement.

QUICK REFERENCE DATA

GND = 0 V; $T_{amb} = 25\text{ °C}$; $t_r = t_f \leq 3.0\text{ ns}$.

SYMBOL	PARAMETER	CONDITIONS	TYPICAL		UNIT
			AHC	AHCT	
t_{PHL}/t_{PLH}	propagation delay D_n to Q_n ; LE to Q_n	$C_L = 15\text{ pF}$; $V_{CC} = 5\text{ V}$	4.2	3.9	ns
C_I	input capacitance	$V_I = V_{CC}$ or GND	3.0	3.0	pF
C_O	output capacitance		4.0	4.0	pF
C_{PD}	power dissipation capacitance	$C_L = 50\text{ pF}$; $f = 1\text{ MHz}$; notes 1 and 2	12	18	pF

Notes

1. C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

$$P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum (C_L \times V_{CC}^2 \times f_o) \text{ where:}$$

f_i = input frequency in MHz;

f_o = output frequency in MHz;

$\sum (C_L \times V_{CC}^2 \times f_o)$ = sum of outputs;

C_L = output load capacitance in pF;

V_{CC} = supply voltage in Volts.

2. The condition is $V_I = \text{GND}$ to V_{CC} .

Octal D-type transparent latch; 3-state

74AHC573; 74AHCT573

FUNCTION TABLE

See note 1.

OPERATING MODES	INPUTS			INTERNAL LATCHES	OUTPUTS
	$\overline{OE}$	LE	D _n		Q ₀ to Q ₇
Enable and read register (transparent mode)	L	H	L	L	L
	L	H	H	H	H
Latch and read register	L	L	l	L	L
	L	L	h	H	H
Latch register and disable outputs	H	L	l	L	Z
	H	L	h	H	Z

Note

1. H = HIGH voltage level;
h = HIGH voltage level one set-up time prior to the HIGH-to-LOW LE transition;
L = LOW voltage level;
l = LOW voltage level one set-up time prior to the HIGH-to-LOW LE transition;
Z = high-impedance OFF-state.

ORDERING INFORMATION

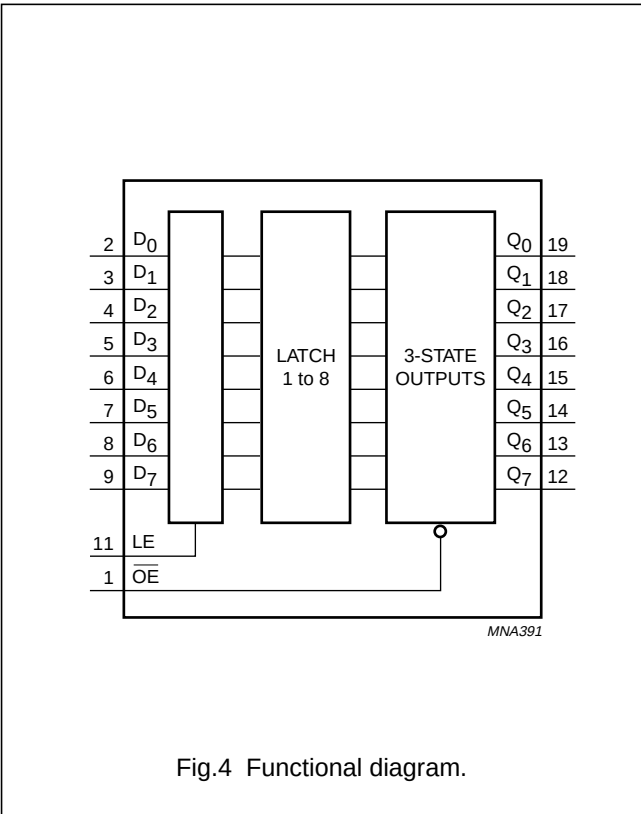
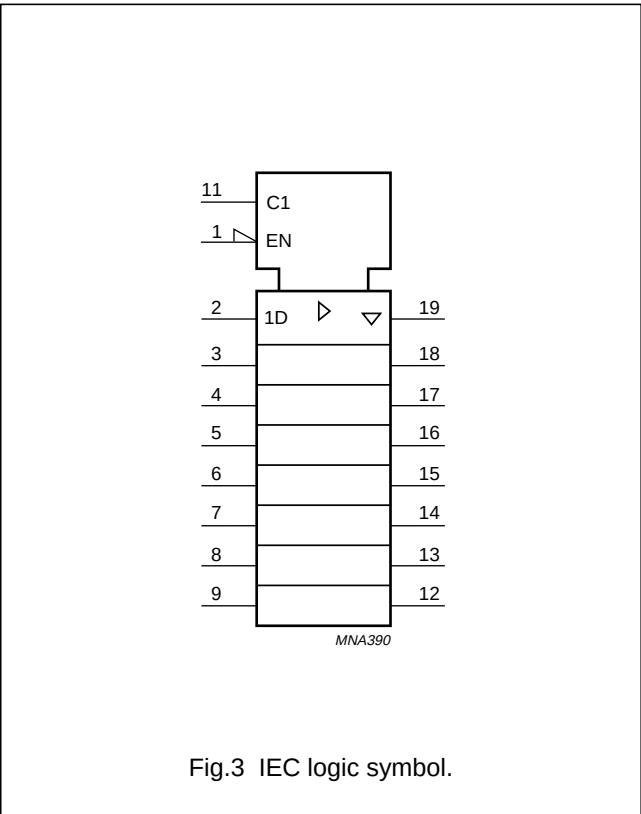
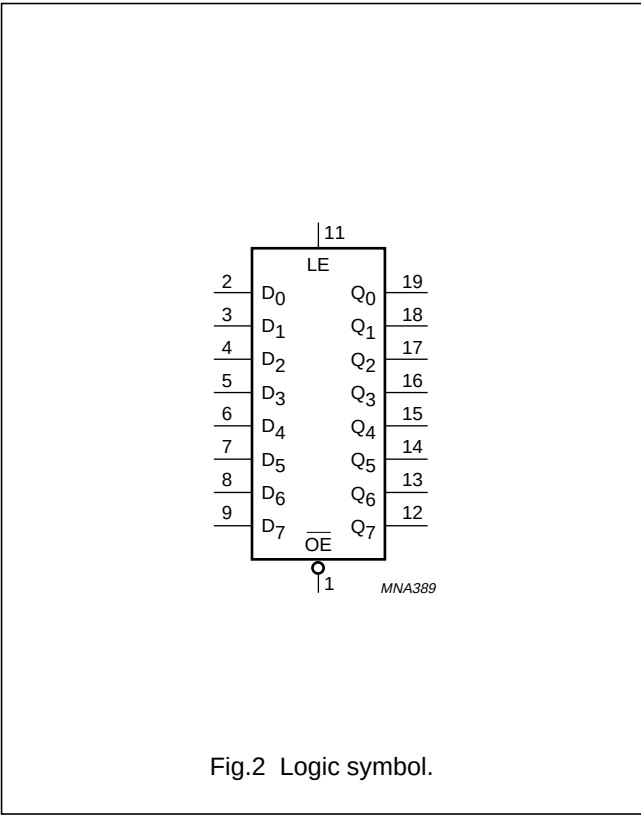
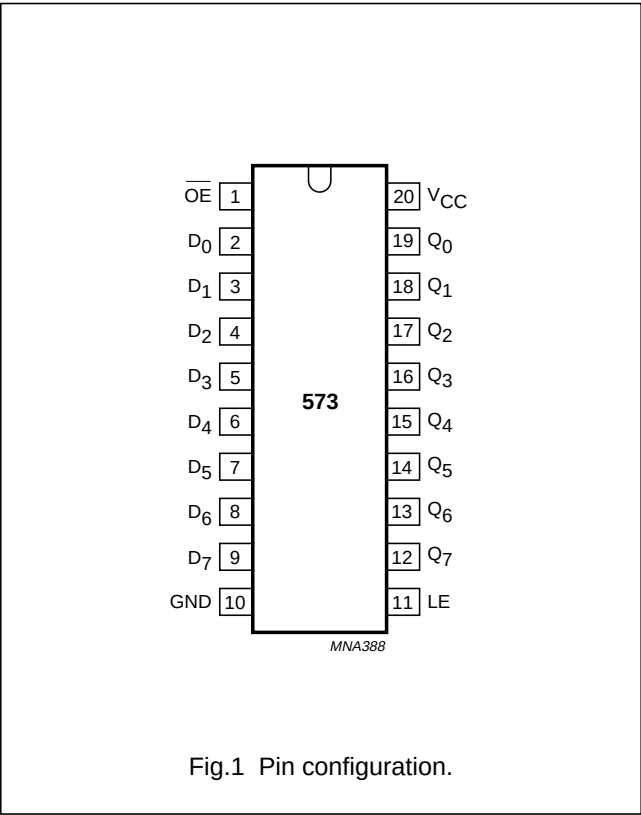
OUTSIDE NORTH AMERICA	NORTH AMERICA	PACKAGES			
		PINS	PACKAGE	MATERIAL	CODE
74AHC573D	74AHC573D	20	SO	plastic	SOT163-1
74AHC573PW	74AHC573PW DH	20	TSSOP	plastic	SOT360-1
74AHCT573D	74AHCT573D	20	SO	plastic	SOT163-1
74AHCT573PW	74AHCT573PW DH	20	TSSOP	plastic	SOT360-1

PINNING

PIN	SYMBOL	DESCRIPTION
1	$\overline{OE}$	3-state output enable input (active LOW)
2 to 9	D ₀ to D ₇	data inputs
10	GND	ground (0 V)
11	LE	latch enable input (active HIGH)
12 to 19	Q ₇ to Q ₀	3-state latch outputs
20	V _{CC}	DC supply voltage

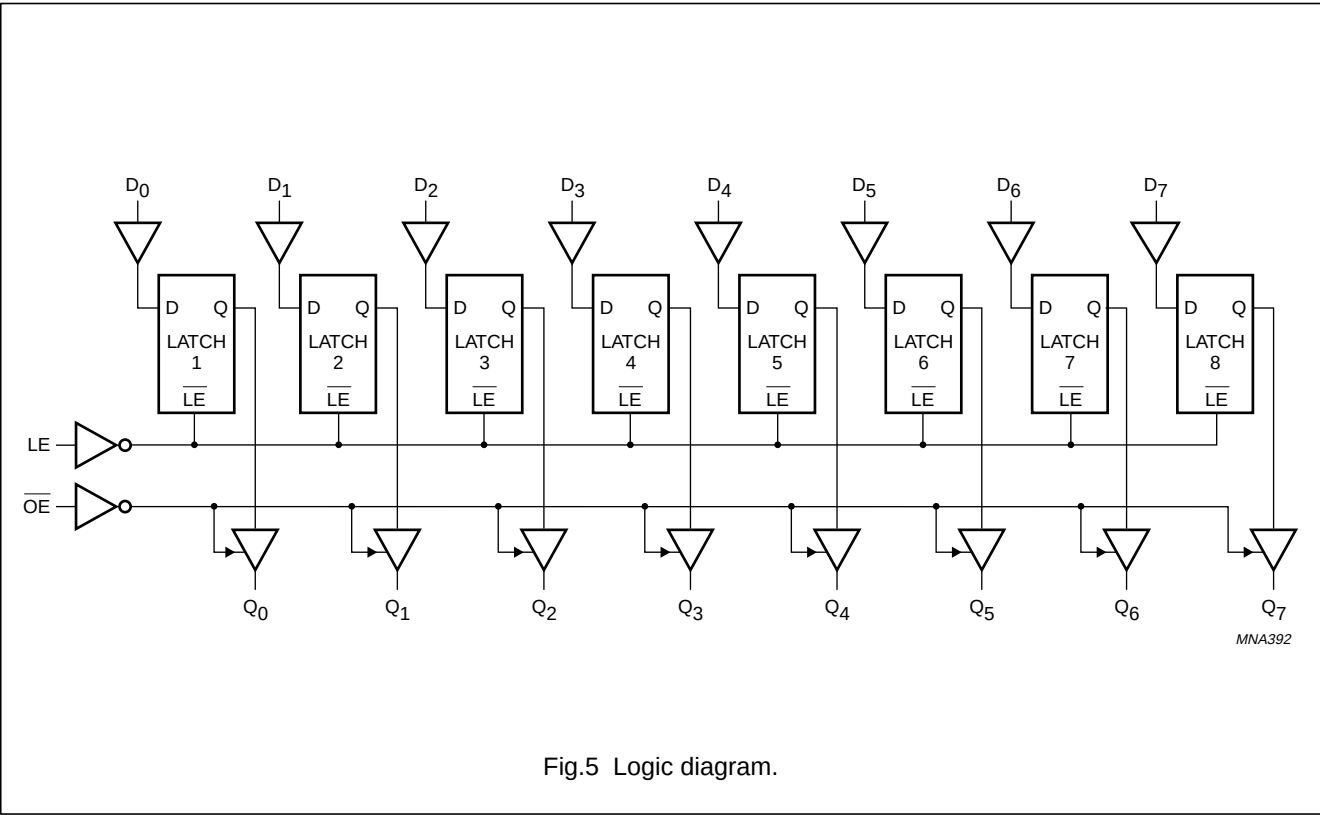
Octal D-type transparent latch; 3-state

74AHC573; 74AHCT573



Octal D-type transparent latch; 3-state

74AHC573; 74AHCT573



RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	74AHC			74AHCT			UNIT
			MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
V _{CC}	DC supply voltage		2.0	5.0	5.5	4.5	5.0	5.5	V
V _I	input voltage		0	–	5.5	0	–	5.5	V
V _O	output voltage		0	–	V _{CC}	0	–	V _{CC}	V
T _{amb}	operating ambient temperature range	see DC and AC characteristics per device	–40	+25	+85	–40	+25	+85	°C
			–40	+25	+125	–40	+25	+125	°C
t _r , t _f (Δt/Δf)	input rise and fall rates	V _{CC} = 3.3 V ±0.3 V	–	–	100	–	–	–	ns/V
		V _{CC} = 5 V ±0.5 V	–	–	20	–	–	20	

Octal D-type transparent latch; 3-state

74AHC573; 74AHCT573

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134); voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{CC}	DC supply voltage		-0.5	+7.0	V
V_I	input voltage range		-0.5	+7.0	V
I_{IK}	DC input diode current	$V_I < -0.5$ V; note 1	–	-20	mA
I_{OK}	DC output diode current	$V_O < -0.5$ V or $V_O > V_{CC} + 0.5$ V; note 1	–	± 20	mA
I_O	DC output source or sink current	-0.5 V $< V_O < V_{CC} + 0.5$ V	–	± 25	mA
I_{CC}	DC V_{CC} or GND current		–	± 75	mA
T_{stg}	storage temperature range		-65	+150	°C
P_D	power dissipation per package	for temperature range: -40 to +125 °C; note 2	–	500	mW

Notes

1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.
2. For SO packages: above 70 °C the value of P_D derates linearly with 8 mW/K.
For TSSOP packages: above 60 °C the value of P_D derates linearly with 5.5 mW/K.

Octal D-type transparent latch; 3-state

74AHC573; 74AHCT573

DC CHARACTERISTICS

74AHC family

Over recommended operating conditions; voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	TEST CONDITIONS		T _{amb} (°C)							UNIT
		OTHER	V _{CC} (V)	25			–40 to +85		–40 to +125		
				MIN.	TYP.	MAX.	MIN.	MAX.	MIN.	MAX.	
V _{IH}	HIGH-level input voltage		2.0	1.5	–	–	1.5	–	1.5	–	V
			3.0	2.1	–	–	2.1	–	2.1	–	
			5.5	3.85	–	–	3.85	–	3.85	–	
V _{IL}	LOW-level input voltage		2.0	–	–	0.5	–	0.5	–	0.5	V
			3.0	–	–	0.9	–	0.9	–	0.9	
			5.5	–	–	1.65	–	1.65	–	1.65	
V _{OH}	HIGH-level output voltage; all outputs	V _I = V _{IH} or V _{IL} ; I _O = –50 μA	2.0	1.9	2.0	–	1.9	–	1.9	–	V
			3.0	2.9	3.0	–	2.9	–	2.9	–	
			4.5	4.4	4.5	–	4.4	–	4.4	–	
	HIGH-level output voltage	V _I = V _{IH} or V _{IL} ; I _O = –4.0 mA	3.0	2.58	–	–	2.48	–	2.40	–	V
		V _I = V _{IH} or V _{IL} ; I _O = –8.0 mA	4.5	3.94	–	–	3.8	–	3.70	–	
V _{OL}	LOW-level output voltage; all outputs	V _I = V _{IH} or V _{IL} ; I _O = 50 μA	2.0	–	0	0.1	–	0.1	–	0.1	V
			3.0	–	0	0.1	–	0.1	–	0.1	
			4.5	–	0	0.1	–	0.1	–	0.1	
	LOW-level output voltage	V _I = V _{IH} or V _{IL} ; I _O = 4 mA	3.0	–	–	0.36	–	0.44	–	0.55	V
		V _I = V _{IH} or V _{IL} ; I _O = 8 mA	4.5	–	–	0.36	–	0.44	–	0.55	
I _I	input leakage current	V _I = V _{CC} or GND	5.5	–	–	0.1	–	1.0	–	2.0	μA
I _{OZ}	3-state output OFF current	V _I = V _{IH} or V _{IL} ; V _O = V _{CC} or GND	5.5	–	–	±0.25	–	±2.5	–	±10.0	μA
I _{CC}	quiescent supply current	V _I = V _{CC} or GND; I _O = 0	5.5	–	–	4.0	–	40	–	80	μA
C _I	input capacitance		–	–	3	10	–	10	–	10	pF

Octal D-type transparent latch; 3-state

74AHC573; 74AHCT573

74AHCT family

Over recommended operating conditions; voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	TEST CONDITIONS		T _{amb} (°C)							UNIT
		OTHER	V _{CC} (V)	25			–40 to +85		–40 to +125		
				MIN.	TYP.	MAX.	MIN.	MAX.	MIN.	MAX.	
V _{IH}	HIGH-level input voltage		4.5 to 5.5	2.0	–	–	2.0	–	2.0	–	V
V _{IL}	LOW-level input voltage		4.5 to 5.5	–	–	0.8	–	0.8	–	0.8	V
V _{OH}	HIGH-level output voltage; all outputs	V _I = V _{IH} or V _{IL} ; I _O = –50 μA	4.5	4.4	4.5	–	4.4	–	4.4	–	V
	HIGH-level output voltage	V _I = V _{IH} or V _{IL} ; I _O = –8.0 mA	4.5	3.94	–	–	3.8	–	3.70	–	V
V _{OL}	LOW-level output voltage; all outputs	V _I = V _{IH} or V _{IL} ; I _O = 50 μA	4.5	–	0	0.1	–	0.1	–	0.1	V
	LOW-level output voltage	V _I = V _{IH} or V _{IL} ; I _O = 8 mA	4.5	–	–	0.36	–	0.44	–	0.55	V
I _I	input leakage current	V _I = V _{IH} or V _{IL}	5.5	–	–	0.1	–	1.0	–	2.0	μA
I _{OZ}	3-state output OFF current	V _I = V _{IH} or V _{IL} ; V _O = V _{CC} or GND per input pin; other inputs at V _{CC} or GND; I _O = 0	5.5	–	–	±0.25	–	±2.5	–	±10.0	μA
I _{CC}	quiescent supply current	V _I = V _{CC} or GND; I _O = 0	5.5	–	–	4.0	–	40	–	80	μA
ΔI _{CC}	additional quiescent supply current per input pin	V _I = V _{CC} – 2.1 V other inputs at V _{CC} or GND; I _O = 0	4.5 to 5.5	–	–	1.35	–	1.5	–	1.5	mA
C _I	input capacitance		–	–	3	10	–	10	–	10	pF

Octal D-type transparent latch; 3-state

74AHC573; 74AHCT573

AC CHARACTERISTICS

74AHC573

GND = 0 V; $t_r = t_f \leq 3.0$ ns.

SYMBOL	PARAMETER	TEST CONDITIONS		T _{amb} (°C)							UNIT
		WAVEFORMS	C _L	25			−40 to +85		−40 to +125		
				MIN.	TYP.	MAX.	MIN.	MAX.	MIN.	MAX.	
V _{CC} = 3.0 to 3.6 V; note 1											
t _{PHL} /t _{PLH}	propagation delay D _n to Q _n	see Figs 6 and 9	15 pF	–	5.5	11.0	1.0	13.0	1.0	14.0	ns
	propagation delay LE to Q _n	see Figs 7 and 9		–	5.8	11.9	1.0	14.0	1.0	15.0	ns
t _{PZH} /t _{PZL}	propagation delay OE to Q _n	see Figs 8 and 9		–	5.8	11.5	1.0	13.5	1.0	14.5	ns
t _{PHZ} /t _{PLZ}	propagation delay OE to Q _n			–	6.8	11.0	1.0	13.0	1.0	14.0	ns
t _{PHL} /t _{PLH}	propagation delay D _n to Q _n	see Figs 6 and 9	50 pF	–	7.8	14.5	1.0	16.5	1.0	18.5	ns
	propagation delay LE to Q _n	see Figs 7 and 9		–	8.3	15.4	1.0	17.5	1.0	19.5	ns
t _{PZH} /t _{PZL}	propagation delay OE to Q _n	see Figs 8 and 9		–	8.3	15.0	1.0	17.0	1.0	19.0	ns
t _{PHZ} /t _{PLZ}	propagation delay OE to Q _n			–	9.7	14.5	1.0	16.5	1.0	18.5	ns
t _W	enable pulse width HIGH	see Figs 7 and 9		5.0	–	–	5.0	–	5.0	–	ns
t _{su}	set-up time D _n to LE	see Fig.9		3.5	–	–	3.5	–	3.5	–	ns
t _h	hold time D _n to LE			1.5	–	–	1.5	–	1.5	–	ns

Octal D-type transparent latch; 3-state

74AHC573; 74AHCT573

SYMBOL	PARAMETER	TEST CONDITIONS		T _{amb} (°C)							UNIT
		WAVEFORMS	C _L	25			–40 to +85		–40 to +125		
				MIN.	TYP.	MAX.	MIN.	MAX.	MIN.	MAX.	
V _{CC} = 4.5 to 5.5 V; note 2											
t _{PHL} /t _{PLH}	propagation delay D _n to Q _n	see Figs 6 and 9	15 pF	–	3.9	6.8	1.0	8.0	1.0	8.5	ns
	propagation delay LE to Q _n	see Figs 7 and 9		–	4.2	7.7	1.0	9.0	1.0	10.0	ns
t _{PZH} /t _{PZL}	propagation delay OE to Q _n	see Figs 8 and 9		–	4.4	7.7	1.0	9.0	1.0	10.0	ns
t _{PHZ} /t _{PLZ}	propagation delay OE to Q _n			–	4.6	7.7	1.0	9.0	1.0	10.0	ns
t _{PHL} /t _{PLH}	propagation delay D _n to Q _n	see Figs 6 and 9	50 pF	–	5.5	8.8	1.0	10.0	1.0	11.0	ns
	propagation delay LE to Q _n	see Figs 7 and 9		–	5.9	9.7	1.0	11.0	1.0	12.5	ns
t _{PZH} /t _{PZL}	propagation delay OE to Q _n	see Figs 8 and 9		–	6.3	9.7	1.0	11.0	1.0	12.5	ns
t _{PHZ} /t _{PLZ}	propagation delay OE to Q _n			–	7.4	9.7	1.0	11.0	1.0	12.5	ns
t _W	enable pulse width HIGH	see Figs 7 and 9		5.0	–	–	5.0	–	5.0	–	ns
t _{su}	set-up time D _n to LE	see Fig.9		3.5	–	–	3.5	–	3.5	–	ns
t _h	hold time D _n to LE			1.5	–	–	1.5	–	1.5	–	ns

Notes

1. Typical values at V_{CC} = 3.3 V.
2. Typical values at V_{CC} = 5.0 V.

Octal D-type transparent latch; 3-state

74AHC573; 74AHCT573

74AHCT573GND = 0 V; $t_r = t_f \leq 3.0$ ns.

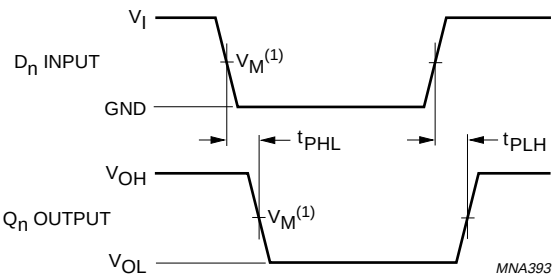
SYMBOL	PARAMETER	TEST CONDITIONS		T _{amb} (°C)							UNIT
		WAVEFORMS	C _L	25			–40 to +85		–40 to +125		
				MIN.	TYP.	MAX.	MIN.	MAX.	MIN.	MAX.	
V _{CC} = 4.5 to 5.5 V; note 1											
t _{PHL} /t _{PLH}	propagation delay D _n to Q _n	see Figs 6 and 9	15 pF	–	3.5	5.5	1	6.5	1	7.0	ns
	propagation delay LE to Q _n	see Figs 7 and 9		–	3.9	6.0	1	7.0	1	7.5	ns
t _{PZH} /t _{PZL}	propagation delay OE to Q _n	see Figs 8 and 9		–	4.1	6.5	1	7.5	1	8.5	ns
t _{PHZ} /t _{PLZ}	propagation delay OE to Q _n			–	4.5	6.5	1	7.5	1	8.5	ns
t _{PHL} /t _{PLH}	propagation delay D _n to Q _n	see Figs 6 and 9	50 pF	–	4.9	7.5	1	8.5	1	9.5	ns
	propagation delay LE to Q _n	see Figs 7 and 9		–	5.5	8.5	1	9.5	1	11.0	ns
t _{PZH} /t _{PZL}	propagation delay OE to Q _n	see Figs 8 and 9		–	5.9	8.5	1	10.0	1	11.0	ns
t _{PHZ} /t _{PLZ}	propagation delay OE to Q _n			–	6.4	9.0	1	10.0	1	11.5	ns
t _W	enable pulse width HIGH	see Figs 7 and 9		5.0	–	–	5.0	–	5.0	–	ns
t _{su}	set-up time D _n to LE	see Fig.9		3.5	–	–	3.5	–	3.5	–	ns
t _h	hold time D _n to LE			1.5	–	–	1.5	–	1.5	–	ns

Note1. Typical values at $V_{CC} = 5.0$ V.

Octal D-type transparent latch; 3-state

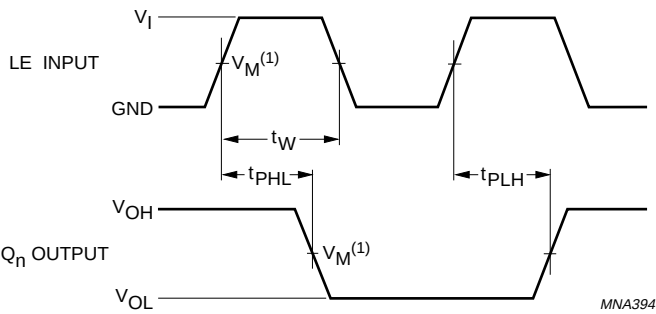
74AHC573; 74AHCT573

AC WAVEFORMS



FAMILY	V_I INPUT REQUIREMENTS	$V_M^{(1)}$ INPUT	$V_M^{(1)}$ OUTPUT
AHC	GND to V_{CC}	50% V_{CC}	50% V_{CC}
AHCT	GND to 3.0 V	1.5 V	50% V_{CC}

Fig.6 The data input (D_n) to output (Q_n) propagation delays.

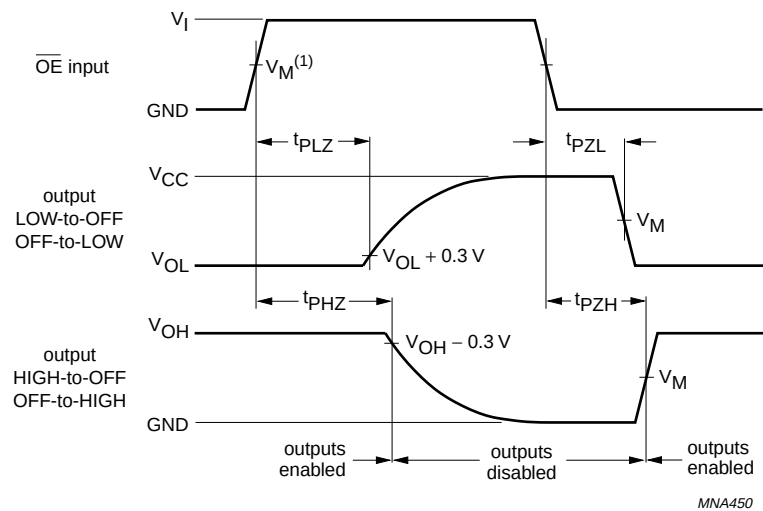


FAMILY	V_I INPUT REQUIREMENTS	$V_M^{(1)}$ INPUT	$V_M^{(1)}$ OUTPUT
AHC	GND to V_{CC}	50% V_{CC}	50% V_{CC}
AHCT	GND to 3.0 V	1.5 V	50% V_{CC}

Fig.7 The latch enable input (LE) pulse width, the latch enable input to output (Q_n) propagation delays.

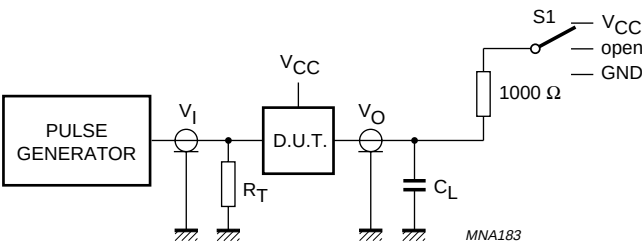
Octal D-type transparent latch; 3-state

74AHC573; 74AHCT573



FAMILY	V _I INPUT REQUIREMENTS	V _M (1) INPUT	V _M (1) OUTPUT
AHC	GND to V _{CC}	50% V _{CC}	50% V _{CC}
AHCT	GND to 3.0 V	1.5 V	50% V _{CC}

Fig.8 The 3-state enable and disable times.



TEST	S ₁
t _{PLH} /t _{PHL}	open
t _{PLZ} /t _{PZL}	V _{CC}
t _{PHZ} /t _{PZH}	GND

Fig.9 Load circuitry for switching times.

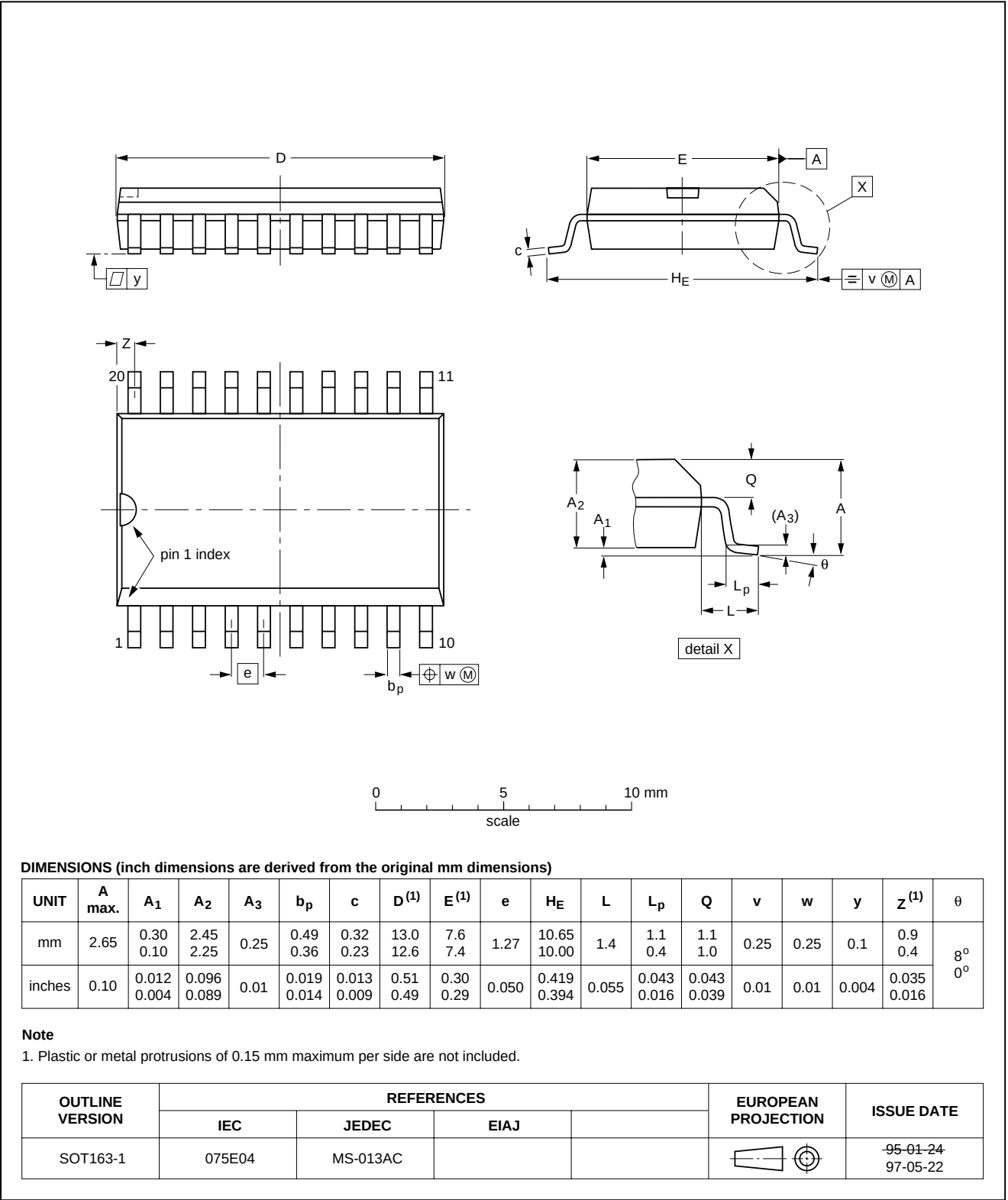
Octal D-type transparent latch; 3-state

74AHC573; 74AHCT573

PACKAGE OUTLINES

SO20: plastic small outline package; 20 leads; body width 7.5 mm

SOT163-1

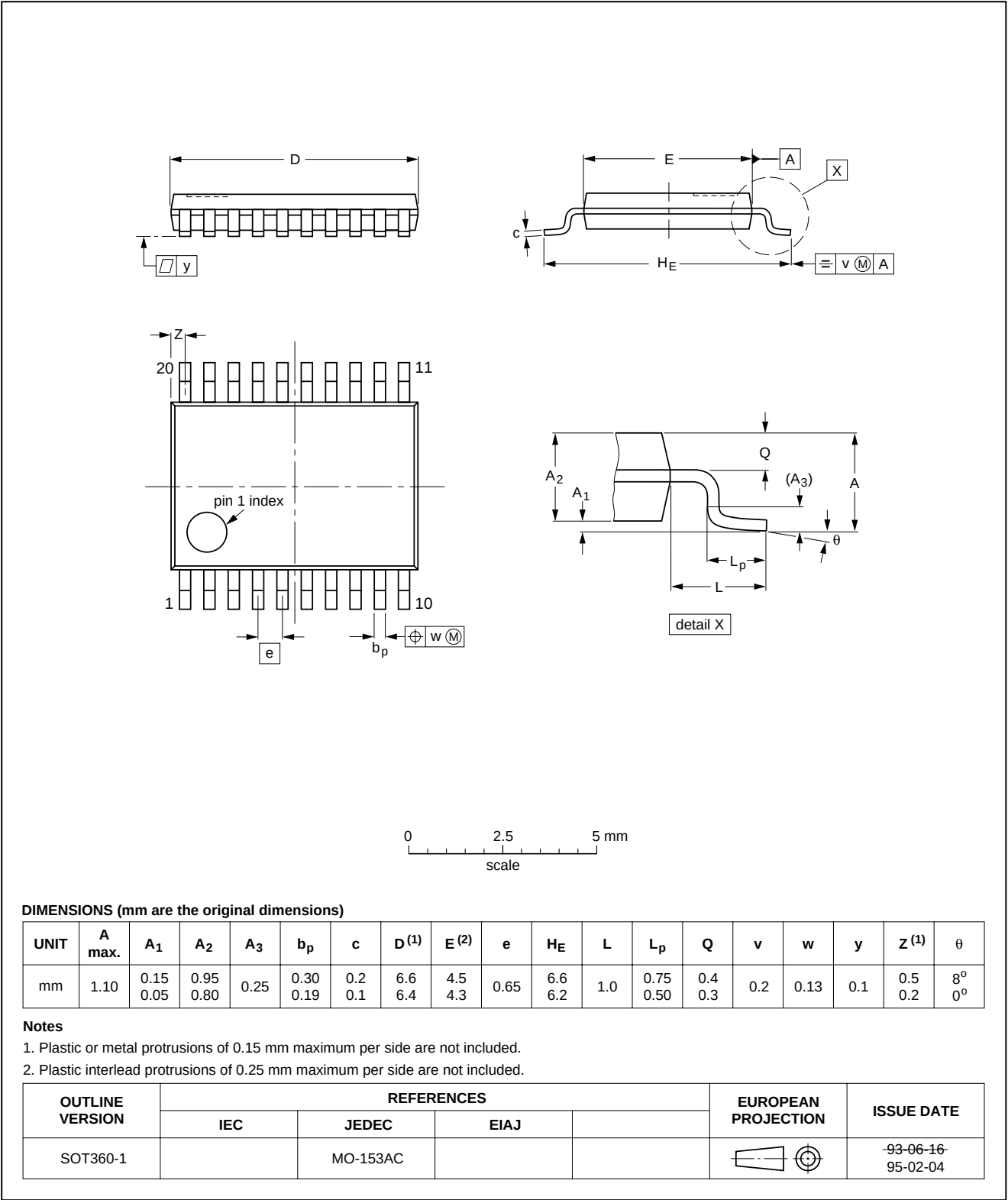


Octal D-type transparent latch; 3-state

74AHC573; 74AHCT573

TSSOP20: plastic thin shrink small outline package; 20 leads; body width 4.4 mm

SOT360-1



Octal D-type transparent latch; 3-state

74AHC573; 74AHCT573

SOLDERING**Introduction to soldering surface mount packages**

This text gives a very brief insight to a complex technology. A more in-depth account of soldering ICs can be found in our *"Data Handbook IC26; Integrated Circuit Packages"* (document order number 9398 652 90011).

There is no soldering method that is ideal for all surface mount IC packages. Wave soldering is not always suitable for surface mount ICs, or for printed-circuit boards with high population densities. In these situations reflow soldering is often used.

Reflow soldering

Reflow soldering requires solder paste (a suspension of fine solder particles, flux and binding agent) to be applied to the printed-circuit board by screen printing, stencilling or pressure-syringe dispensing before package placement.

Several methods exist for reflowing; for example, infrared/convection heating in a conveyor type oven. Throughput times (preheating, soldering and cooling) vary between 100 and 200 seconds depending on heating method.

Typical reflow peak temperatures range from 215 to 250 °C. The top-surface temperature of the packages should preferably be kept below 230 °C.

Wave soldering

Conventional single wave soldering is not recommended for surface mount devices (SMDs) or printed-circuit boards with a high component density, as solder bridging and non-wetting can present major problems.

To overcome these problems the double-wave soldering method was specifically developed.

If wave soldering is used the following conditions must be observed for optimal results:

- Use a double-wave soldering method comprising a turbulent wave with high upward pressure followed by a smooth laminar wave.
- For packages with leads on two sides and a pitch (e):
 - larger than or equal to 1.27 mm, the footprint longitudinal axis is **preferred** to be parallel to the transport direction of the printed-circuit board;
 - smaller than 1.27 mm, the footprint longitudinal axis **must** be parallel to the transport direction of the printed-circuit board.

The footprint must incorporate solder thieves at the downstream end.

- For packages with leads on four sides, the footprint must be placed at a 45° angle to the transport direction of the printed-circuit board. The footprint must incorporate solder thieves downstream and at the side corners.

During placement and before soldering, the package must be fixed with a droplet of adhesive. The adhesive can be applied by screen printing, pin transfer or syringe dispensing. The package can be soldered after the adhesive is cured.

Typical dwell time is 4 seconds at 250 °C.

A mildly-activated flux will eliminate the need for removal of corrosive residues in most applications.

Manual soldering

Fix the component by first soldering two diagonally-opposite end leads. Use a low voltage (24 V or less) soldering iron applied to the flat part of the lead. Contact time must be limited to 10 seconds at up to 300 °C.

When using a dedicated tool, all other leads can be soldered in one operation within 2 to 5 seconds between 270 and 320 °C.

Octal D-type transparent latch; 3-state

74AHC573; 74AHCT573

Suitability of surface mount IC packages for wave and reflow soldering methods

PACKAGE	SOLDERING METHOD	
	WAVE	REFLOW ⁽¹⁾
BGA, LFBGA, SQFP, TFBGA	not suitable	suitable
HLQFP, HSQFP, HSOP, HTQFP, HTSSOP, SMS	not suitable ⁽²⁾	suitable
PLCC ⁽³⁾ , SO, SOJ	suitable	suitable
LQFP, QFP, TQFP	not recommended ⁽³⁾⁽⁴⁾	suitable
SSOP, TSSOP, VSO	not recommended ⁽⁵⁾	suitable

Notes

1. All surface mount (SMD) packages are moisture sensitive. Depending upon the moisture content, the maximum temperature (with respect to time) and body size of the package, there is a risk that internal or external package cracks may occur due to vaporization of the moisture in them (the so called popcorn effect). For details, refer to the Drypack information in the *"Data Handbook IC26; Integrated Circuit Packages; Section: Packing Methods"*.
2. These packages are not suitable for wave soldering as a solder joint between the printed-circuit board and heatsink (at bottom version) can not be achieved, and as solder may stick to the heatsink (on top version).
3. If wave soldering is considered, then the package must be placed at a 45° angle to the solder wave direction. The package footprint must incorporate solder thieves downstream and at the side corners.
4. Wave soldering is only suitable for LQFP, TQFP and QFP packages with a pitch (e) equal to or larger than 0.8 mm; it is definitely not suitable for packages with a pitch (e) equal to or smaller than 0.65 mm.
5. Wave soldering is only suitable for SSOP and TSSOP packages with a pitch (e) equal to or larger than 0.65 mm; it is definitely not suitable for packages with a pitch (e) equal to or smaller than 0.5 mm.

DEFINITIONS

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
Application information	
Where application information is given, it is advisory and does not form part of the specification.	

LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.

Octal D-type transparent latch; 3-state

74AHC573; 74AHCT573

NOTES

Octal D-type transparent latch; 3-state

74AHC573; 74AHCT573

NOTES

Philips Semiconductors – a worldwide company

Argentina: see South America

Australia: 3 Figtree Drive, HOMEBUSH, NSW 2140,
Tel. +61 2 9704 8141, Fax. +61 2 9704 8139

Austria: Computerstr. 6, A-1101 WIEN, P.O. Box 213,
Tel. +43 1 60 101 1248, Fax. +43 1 60 101 1210

Belarus: Hotel Minsk Business Center, Bld. 3, r. 1211, Volodarski Str. 6,
220050 MINSK, Tel. +375 172 20 0733, Fax. +375 172 20 0773

Belgium: see The Netherlands

Brazil: see South America

Bulgaria: Philips Bulgaria Ltd., Energoproject, 15th floor,
51 James Bourchier Blvd., 1407 SOFIA,
Tel. +359 2 68 9211, Fax. +359 2 68 9102

Canada: PHILIPS SEMICONDUCTORS/COMPONENTS,
Tel. +1 800 234 7381, Fax. +1 800 943 0087

China/Hong Kong: 501 Hong Kong Industrial Technology Centre,
72 Tat Chee Avenue, Kowloon Tong, HONG KONG,
Tel. +852 2319 7888, Fax. +852 2319 7700

Colombia: see South America

Czech Republic: see Austria

Denmark: Sydhavnsgade 23, 1780 COPENHAGEN V,
Tel. +45 33 29 3333, Fax. +45 33 29 3905

Finland: Sinikalliontie 3, FIN-02630 ESPOO,
Tel. +358 9 615 800, Fax. +358 9 6158 0920

France: 51 Rue Carnot, BP317, 92156 SURESNES Cedex,
Tel. +33 1 4099 6161, Fax. +33 1 4099 6427

Germany: Hammerbrookstraße 69, D-20097 HAMBURG,
Tel. +49 40 2353 60, Fax. +49 40 2353 6300

Hungary: see Austria

India: Philips INDIA Ltd, Band Box Building, 2nd floor,
254-D, Dr. Annie Besant Road, Worli, MUMBAI 400 025,
Tel. +91 22 493 8541, Fax. +91 22 493 0966

Indonesia: PT Philips Development Corporation, Semiconductors Division,
Gedung Philips, Jl. Buncit Raya Kav.99-100, JAKARTA 12510,
Tel. +62 21 794 0040 ext. 2501, Fax. +62 21 794 0080

Ireland: Newstead, Clonskeagh, DUBLIN 14,
Tel. +353 1 7640 000, Fax. +353 1 7640 200

Israel: RAPAC Electronics, 7 Kehilat Saloniki St, PO Box 18053,
TEL AVIV 61180, Tel. +972 3 645 0444, Fax. +972 3 649 1007

Italy: PHILIPS SEMICONDUCTORS, Via Casati, 23 - 20052 MONZA (MI),
Tel. +39 039 203 6838, Fax +39 039 203 6800

Japan: Philips Bldg 13-37, Kohnan 2-chome, Minato-ku,
TOKYO 108-8507, Tel. +81 3 3740 5130, Fax. +81 3 3740 5057

Korea: Philips House, 260-199 Itaewon-dong, Yongsan-ku, SEOUL,
Tel. +82 2 709 1412, Fax. +82 2 709 1415

Malaysia: No. 76 Jalan Universiti, 46200 PETALING JAYA, SELANGOR,
Tel. +60 3 750 5214, Fax. +60 3 757 4880

Mexico: 5900 Gateway East, Suite 200, EL PASO, TEXAS 79905,
Tel. +9-5 800 234 7381, Fax +9-5 800 943 0087

Middle East: see Italy

Netherlands: Postbus 90050, 5600 PB EINDHOVEN, Bldg. VB,
Tel. +31 40 27 82785, Fax. +31 40 27 88399

New Zealand: 2 Wagener Place, C.P.O. Box 1041, AUCKLAND,
Tel. +64 9 849 4160, Fax. +64 9 849 7811

Norway: Box 1, Manglerud 0612, OSLO,
Tel. +47 22 74 8000, Fax. +47 22 74 8341

Pakistan: see Singapore

Philippines: Philips Semiconductors Philippines Inc.,
106 Valero St. Salcedo Village, P.O. Box 2108 MCC, MAKATI,
Metro MANILA, Tel. +63 2 816 6380, Fax. +63 2 817 3474

Poland: Al.Jerozolimskie 195 B, 02-222 WARSAW,
Tel. +48 22 5710 000, Fax. +48 22 5710 001

Portugal: see Spain

Romania: see Italy

Russia: Philips Russia, Ul. Usatcheva 35A, 119048 MOSCOW,
Tel. +7 095 755 6918, Fax. +7 095 755 6919

Singapore: Lorong 1, Toa Payoh, SINGAPORE 319762,
Tel. +65 350 2538, Fax. +65 251 6500

Slovakia: see Austria

Slovenia: see Italy

South Africa: S.A. PHILIPS Pty Ltd., 195-215 Main Road Martindale,
2092 JOHANNESBURG, P.O. Box 58088 Newville 2114,
Tel. +27 11 471 5401, Fax. +27 11 471 5398

South America: Al. Vicente Pinzon, 173, 6th floor,
04547-130 SÃO PAULO, SP, Brazil,
Tel. +55 11 821 2333, Fax. +55 11 821 2382

Spain: Balmes 22, 08007 BARCELONA,
Tel. +34 93 301 6312, Fax. +34 93 301 4107

Sweden: Kottbygatan 7, Akalla, S-16485 STOCKHOLM,
Tel. +46 8 5985 2000, Fax. +46 8 5985 2745

Switzerland: Allmendstrasse 140, CH-8027 ZÜRICH,
Tel. +41 1 488 2741 Fax. +41 1 488 3263

Taiwan: Philips Semiconductors, 6F, No. 96, Chien Kuo N. Rd., Sec. 1,
TAIPEI, Taiwan Tel. +886 2 2134 2886, Fax. +886 2 2134 2874

Thailand: PHILIPS ELECTRONICS (THAILAND) Ltd.,
209/2 Sanpavuth-Bangna Road Prakanong, BANGKOK 10260,
Tel. +66 2 745 4090, Fax. +66 2 398 0793

Turkey: Yukari Dudullu, Org. San. Blg., 2.Cad. Nr. 28 81260 Umraniye,
ISTANBUL, Tel. +90 216 522 1500, Fax. +90 216 522 1813

Ukraine: PHILIPS UKRAINE, 4 Patrice Lumumba str., Building B, Floor 7,
252042 KIEV, Tel. +380 44 264 2776, Fax. +380 44 268 0461

United Kingdom: Philips Semiconductors Ltd., 276 Bath Road, Hayes,
MIDDLESEX UB3 5BX, Tel. +44 208 730 5000, Fax. +44 208 754 8421

United States: 811 East Arques Avenue, SUNNYVALE, CA 94088-3409,
Tel. +1 800 234 7381, Fax. +1 800 943 0087

Uruguay: see South America

Vietnam: see Singapore

Yugoslavia: PHILIPS, Trg N. Pasica 5/v, 11000 BEOGRAD,
Tel. +381 11 62 5344, Fax.+381 11 63 5777

For all other countries apply to: Philips Semiconductors,
International Marketing & Sales Communications, Building BE-p, P.O. Box 218,
5600 MD EINDHOVEN, The Netherlands, Fax. +31 40 27 24825

Internet: <http://www.semiconductors.philips.com>

© Philips Electronics N.V. 1999

SCA 68

All rights are reserved. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner.

The information presented in this document does not form part of any quotation or contract, is believed to be accurate and reliable and may be changed without notice. No liability will be accepted by the publisher for any consequence of its use. Publication thereof does not convey nor imply any license under patent- or other industrial or intellectual property rights.

Printed in The Netherlands

245002/01/pp20

Date of release: 1999 Sep 27

Document order number: 9397 750 05739

Let's make things better.

**Philips
Semiconductors**



PHILIPS